

isc N-Channel MOSFET Transistor

SPD07N60S5,ISPD07N60S5

FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leq 0.6\Omega$
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

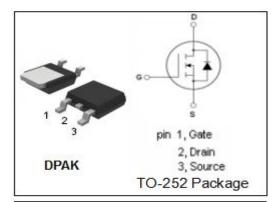
· Improved transconductance

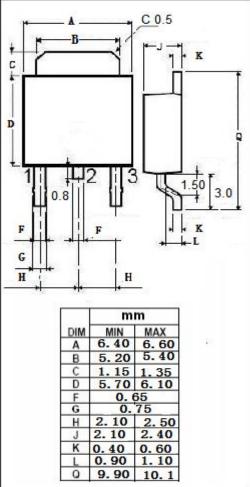
• ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}C$)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous	7.3	Α	
I _{DM}	Drain Current-Single Pulsed 14		А	
P _D	Total Dissipation @T _C =25°C	ssipation @T _C =25°C 83		
Tj	Max. Operating Junction Temperature 150		$^{\circ}$	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.5	°C/W
Rth(j-a)	Rth(j-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.35mA	3.5		5.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =4.6A			0.6	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =20V; V _{DS} =0V			0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			1	μА
V _{SD}	Diode forward voltage	$I_F=I_S$, $V_{GS}=0V$			1.2	V

NOTICE:

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